

**Features:**

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent

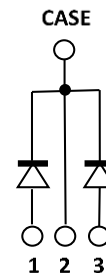
Switching

**Benefits:**

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
$V_{RRM}$	650	V
$I_F$ ( $T_C = 155^\circ\text{C}$ )	12	A
$*Q_C$	13	nC

**Outline**

**TO-247-3**
**Circuit**

**Applications:**

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

**Maximum Ratings (\*Per leg)**

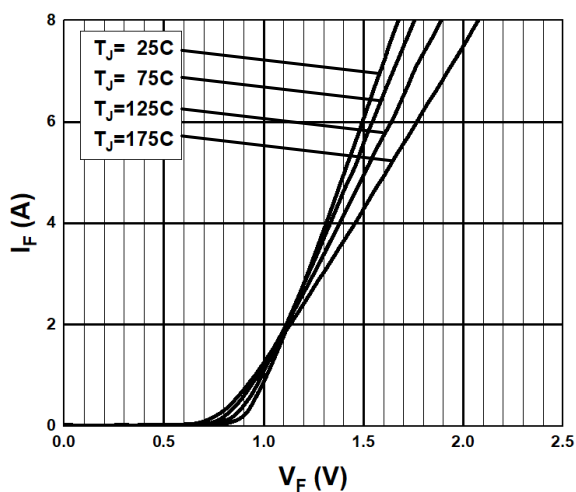
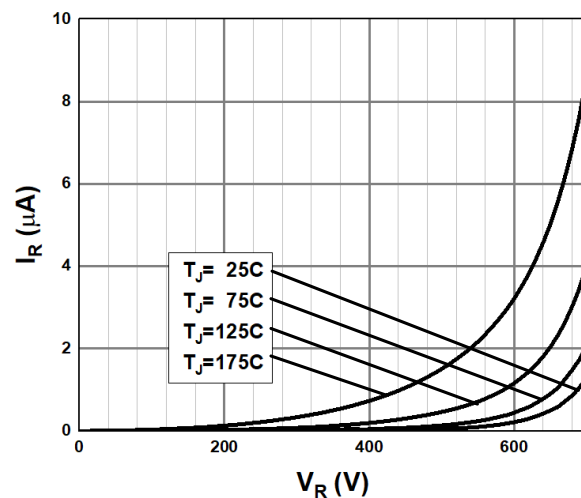
Symbol	Parameter	Value	Unit	Test Conditions
$V_R$	DC Peak Reverse Voltage	650	V	$T_J = 25^\circ\text{C}$
$V_{RRM}$	Repetitive Peak Reverse	650	V	$T_J = 25^\circ\text{C}$
$V_{RSM}$	Surge Peak Reverse Voltage	650	V	$T_J = 25^\circ\text{C}$
$I_F$	Continuous Forward Current	*20/40 *9.5/19 *6/12	A	$T_C = 25^\circ\text{C}$ $T_C = 135^\circ\text{C}$ $T_C = 155^\circ\text{C}$
$I_{FRM}$	Repetitive Peak Forward Surge Current	*38 *34	A	$T_C = 25^\circ\text{C}$ , $T_P = 10\text{ms}$ , Half Sine Wave $T_C = 125^\circ\text{C}$ , $T_P = 10\text{ms}$ , Half Sine Wave
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current	*49 *44	A	$T_C = 25^\circ\text{C}$ , $T_P = 10\text{ms}$ , Half Sine Wave $T_C = 125^\circ\text{C}$ , $T_P = 10\text{ms}$ , Half Sine Wave
$P_D$	Power Dissipation	*83 *27	W	$T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$
$T_{J,max}$	Operating Junction Temperature	175	$^\circ\text{C}$	
$T_{stg}$	Storage Temperature Range	-55 to 175	$^\circ\text{C}$	

**Thermal characteristics (\*Per leg)**

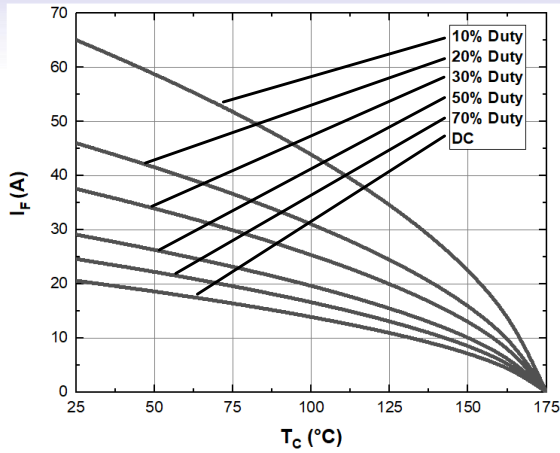
Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{thJC}$	Thermal resistance		*1.8/0.9		°C/W

**Electrical Characteristics (Per leg)**

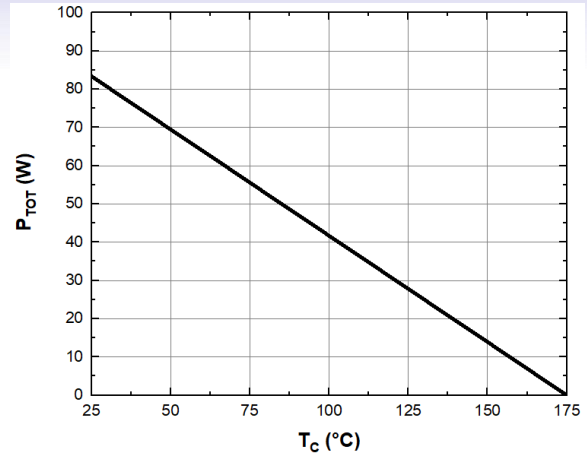
Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
$V_{DC}$	DC Blocking Voltage	650			V	$I_R = 100\mu A$ , $T_J = 25^\circ C$
$V_F$	Forward Voltage		1.5 1.9	1.8 2.2	V	$I_F = 6A$ , $T_J = 25^\circ C$ $I_F = 6A$ , $T_J = 175^\circ C$
$I_R$	Reverse Current		1 10	30 200	$\mu A$	$V_R = 650V$ , $T_J = 25^\circ C$ $V_R = 650V$ , $T_J = 175^\circ C$
$Q_C$	Total Capacitive Charge		13		nC	$I_F = 6A$ , $dI/dt = 250A/\mu s$ $T_J = 25^\circ C$ , $V_R = 400V$
$C$	Total Capacitance		148 33 32		pF	$V_R = 1V$ , $T_J = 25^\circ C$ , $f = 1 MHz$ $V_R = 200V$ , $T_J = 25^\circ C$ , $f = 1 MHz$ $V_R = 400V$ , $T_J = 25^\circ C$ , $f = 1 MHz$

**Typical Performance (Per leg)**

**Fig. 1 Forward Characteristics**

**Fig. 2 Reverse Characteristics**

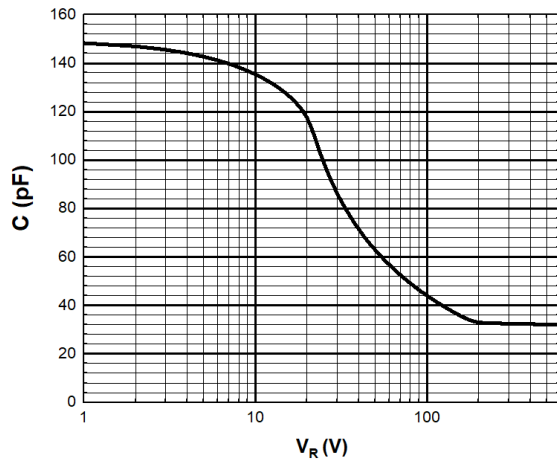
### Typical Performance (per leg)



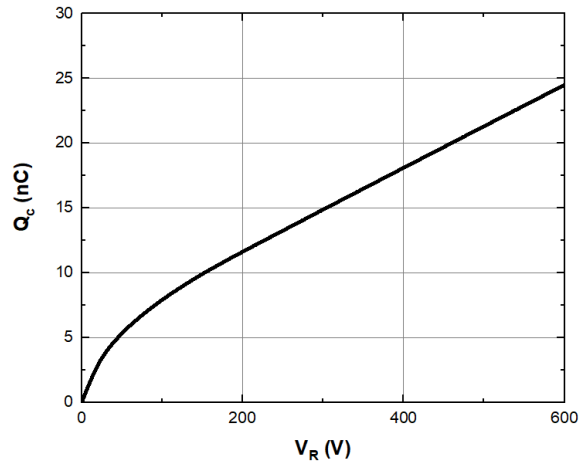
**Fig. 3 Current Derating**



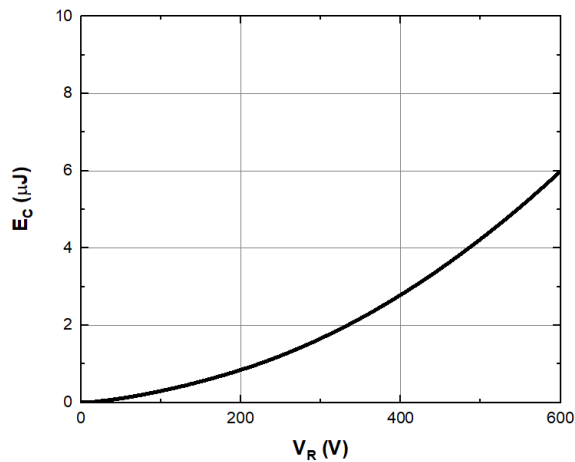
**Fig. 4 Power Derating**



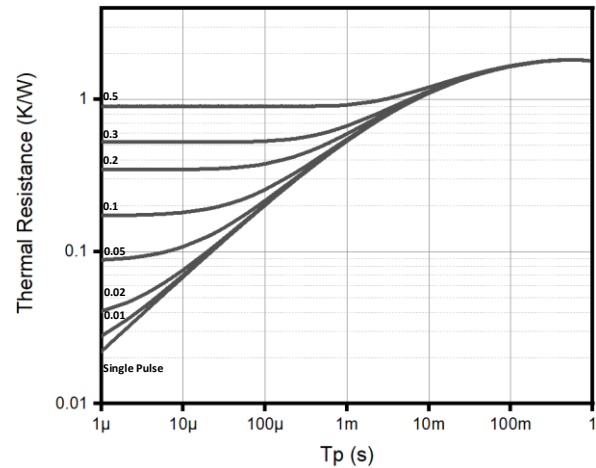
**Fig. 5 Capacitance vs. Reverse Voltage**



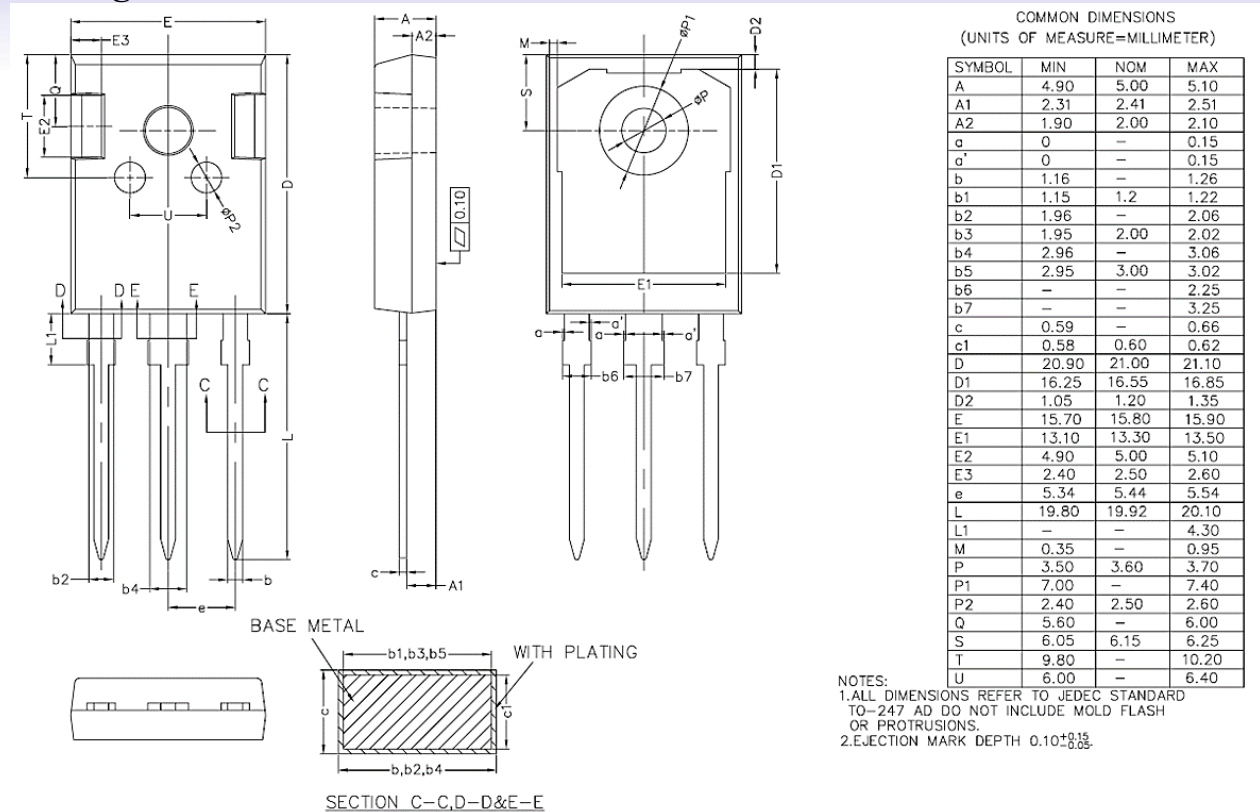
**Fig. 6 Recovery Charge vs. Reverse Voltage**



**Fig. 7 Capacitance stored Energy**



**Fig. 8 Transient Thermal impedance**

**Package TO-247-3 (Unit: mm)**


This Product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, systems, or air-traffic control systems.

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